

# Magnetic Fluctuations in ZnGeP<sub>2</sub>:Mn

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## Project Focus

- Dilute Magnetic Semiconducting (DMS) systems gaining importance as prospects in spin-based electronics
- Mechanism responsible for connecting local magnetic features to bulk magnetic properties – not yet understood in DMS systems

## MuSR & $\mu^+$ as Local Probe [1]

- Muon Spin Relaxation utilizes unique sensitivity of 100% spin polarized and positively charged muons to probe local magnetic and electronic environment

- Local B-field environment for  $\mu$ :

$$\mathbf{B}_{loc} = \langle \mathbf{B}_{loc} \rangle + \delta \mathbf{B}_{loc} = \mathbf{B}_{ext} + \mathbf{B}_{dip} + \mathbf{B}_{hyp} + \mathbf{B}_{fermi} + \delta \mathbf{B}_{loc}$$

$\mathbf{B}_{ext}$  = Applied external field

$\mathbf{B}_{dip}$  = dipolar field

→ Sum of localized moments over entire crystal

→ Including site to site differences

$\mathbf{B}_{hyp}$  = Field from HF interaction

→ Short range magnetic interaction between  $\mu^+$  and local electronic moments

(cf: wavefunction overlap)

$\mathbf{B}_{fermi}$  = Fermi contact interaction

→ Mag. interaction of  $\mu^+$  &  $e^-$  spins for  $s$  &  $p$   $e^-$  metals

→ RKKY – indirect exchange between  $\mu^+$  and unpaired  $e^-$  via conduction  $e^-$  [ $d$  &  $f$  materials]

→ Transferred hyperfine field [ $\mu^+$  &  $e^-$  wavefunction overlap in insulators]

$\delta \mathbf{B}_{loc}$  = Contribution from fluctuation in neighboring magnetic moments →  $\nu$

## Material Properties: ZnGeP<sub>2</sub>:Mn

- $E_g \approx 1.83\text{eV}$  to  $2.0\text{eV}$  (decreases as Mn conc. increases) [2]
- FM order above RT ( $T_c \approx 310\text{K}$  to  $350\text{K}$ ) [2]
- AFM below  $47\text{K}$  for Mn > 5% [2]
- PM/AFM below  $47\text{K}$  mixed state for Mn < 5% [2]
- Prime candidate for spin-based electronics
  - (1) Semiconducting properties
  - (2) FM and AFM characteristics
- Mn<sup>2+</sup> substitution:
  - (1) Group II: Isovalent (high concentration of Mn<sup>2+</sup>)
  - (2) Group IV: Double Acceptor (light concentration of Mn<sup>2+</sup>)
  - (3) Result of (1) and (2) [ie hole abundance] is strong FM coupling instead of the AFM order produced by group II substitution only
- Powder XRD results [3] support 2<sup>nd</sup> ordering transition but lacks evidence to conclusively demonstrate if small inclusions of MnP dominate magnetic features
- NMR [4] Suggests 90+% Mn atoms in MnP impurity phase with nm sized clusters for 8% to 15% Mn; no additional information for samples with Mn concentration < 8%

## The Experiment

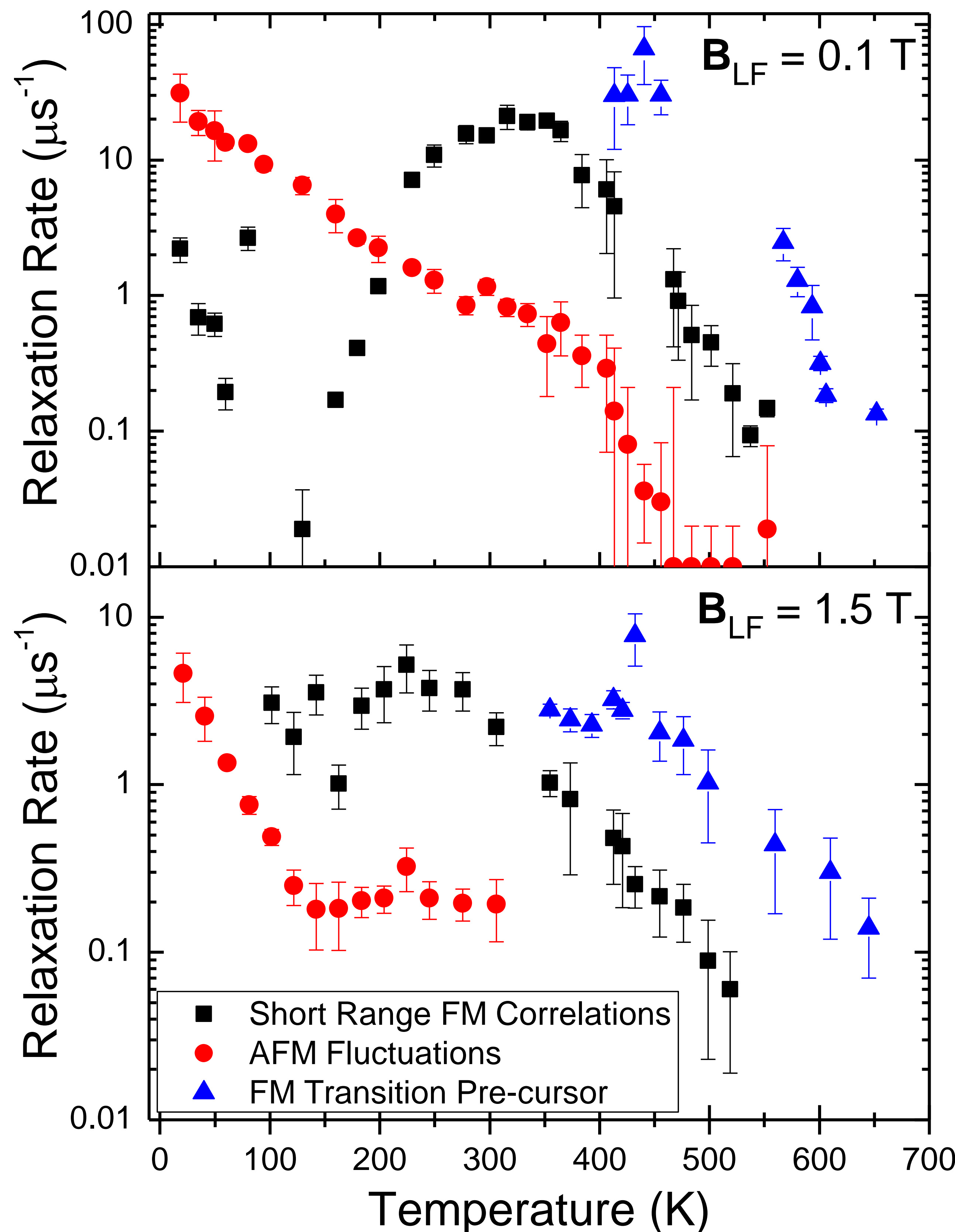
- LF muon spin relaxation measurements:
  - EMU & HiFi spectrometers on surface muon channel at ISIS in Didcot, UK
  - Helios spectrometer on M20 surface muon channel at TRIUMF in Vancouver, Canada
- 4 different ZnGeP<sub>2</sub>:Mn samples, varying Mn concentration
- Temperature scans: ~2 K to 700 K at  $\mathbf{B}_{LF} = \{0.1, 0.375, 0.7, 1.5\}$  T
- B-field scans at various temperatures
- Time dependent muon spin polarization,  $P(t)$ , fit with up to 3 Lorentzian relaxing and 1 non-relaxing component

## Samples

- BAE Systems provided 6 high quality, p-type ZnGeP<sub>2</sub>:Mn
- All samples cut from the same single crystal boule from starting melt of 1.6% Mn grown by horizontal gradient freeze technique
- Each with different Mn content ( $9 \times \sim 13 \times 1.1 \text{ mm}^3$ )

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## Observed Features Consistent Across all Samples

### AFM Fluctuations (●)[5]:

- $\frac{1}{T_1} \sim \frac{2\Delta_i^2}{\nu} |T^I_j = \mu^+ \text{ Rlx rate}; \nu = \text{Spin fluctuation rate}$
- $\Delta_i = \gamma_\mu \delta \mathbf{B}_i = (\mu \text{ gyromagnetic ratio})(\text{RMS value of fluctuating field})$

### Short Range FM Correlations (■):

- Further analysis and modeling required to positively identify and further characterize short range correlations

### FM Transition Precursors (▲):

- Further analysis and modeling required to positively identify and further characterize fluctuations above 350 K
- Preliminary analysis of spin precession data hint at SP at  $T > 300 \text{ K}$
- SQUID Measurements at 350 K show field induced FM that collapses to 0 at zero applied field

## Future Work and Open Questions

- Overall: Improve understanding of magnetism within DMS systems
- Additional data analysis: improve separation of relaxation rates in regions containing more than 2 components; ie. 300K to 500K
- Modeling of fluctuations in DMS systems for AFM, FM, SP
- Link between dilute local moments and bulk magnetism?
- How is magnetism distributed throughout sample?, ie:
  - (1) MnP impurity phase with clustering throughout?
  - (2) Distributed relatively uniformly throughout?

## References

- [1] A. Schenk, *Muon Spin Rotation Spectroscopy: Principles and Applications* [...] (Adam Hilger Ltd, Bristol, 1985).
- [2] Cho, et al., *Phys Rev Lett.* **88** (2002) 257203
- [3] Aitken, et al., *Chem Mater* **19** (2007) 5272-5278
- [4] Hwang, et al *Appl Phys Lett* **83** (2003) 1809-1811
- [5] Uemura, *Phys Rev B.* **31** (1985) 546; Moriya, *Prog. Theor. Phys.* **16** (1956) 23